

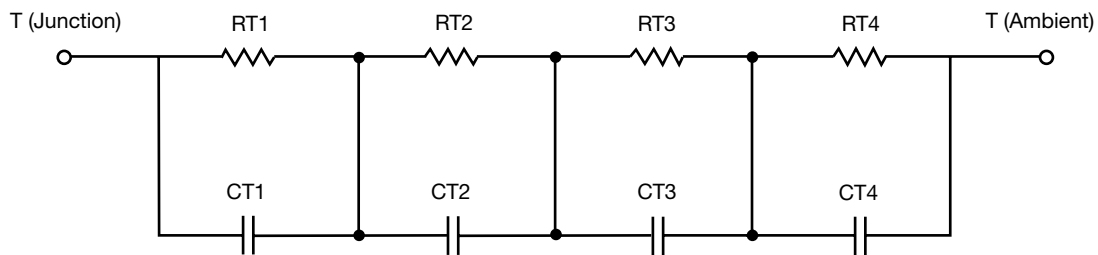
## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	4.0885	1.9005	N/A
RT2	7.9789	864.2827 m	N/A
RT3	12.1571	436.9764 m	N/A
RT4	60.7755	998.2399 m	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	2.6930 m	764.7782 u	N/A
CT2	26.0948 m	49.6821 m	N/A
CT3	127.3571 m	9.8484	N/A
CT4	1.0056	9.6842 m	N/A

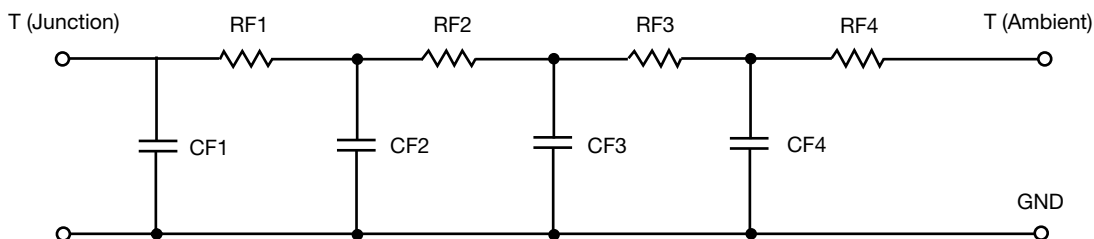
#### Note

- N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*



**R-C THERMAL MODEL FOR FILTER CONFIGURATION**



<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	5.4980	1.6388	N/A
RF2	11.2297	1.1199	N/A
RF3	13.0829	992.9340 m	N/A
RF4	55.1894	430.8350 m	N/A
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	2.6780 m	643.9319 u	N/A
CF2	22.1709 m	1.5952 m	N/A
CF3	166.4422 m	29.4975 m	N/A
CF4	930.2138 m	10.3692	N/A

**Note**

- N/A indicates not applicable

